

FGW35N60H

Discrete IGBT

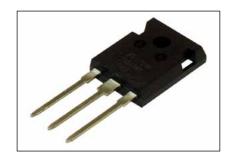
Discrete IGBT (High-Speed V series) 600V / 35A

■ Features

Low power loss Low switching surge and noise High reliability, high ruggedness (RBSOA, SCSOA etc.)

Applications

Uninterruptible power supply Power coditionner Power factor correction circuit

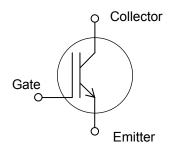


■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter voltage	Vces	600	V	
Gate-Emitter voltage	V _{GES}	±20	V	
DC Collector Current	Ic@25	64	Α	Tc=25°C, Tj=150°C
	Ic@100	35	Α	Tc=100°C, Tj=150°C
Pulsed Collector Current	I _{CP}	105	Α	Note *1
Turn-Off Safe Operating Area	-	105	Α	Vce≤600V, Tj≤175°C
Short Circuit Withstand Time	tsc	5	μs	Vcc≤300V, VgE=12V Tj≤150°C
Maximum Power Dissipation	P□	230	W	Tc=25°C
Operating Junction Temperature	T _j	-40~+175	ç	
Storage Temperature	T _{stg}	-55~+175	ç	

■ Equivalent circuit



Note *1 : Pulse width limited by Tjmax.

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

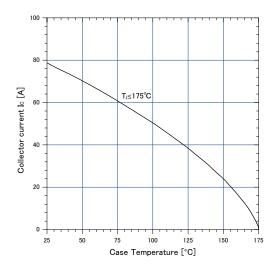
Items	Cumbala	Conditions $I_{C} = 250\mu\text{A}, V_{GE} = 0\text{V}$		Characteristics			Unit	
iteriis	Symbols			min.	typ.	max.	V	
Collector-Emitter Breakdown Voltage	V _{(BR)CES}			600	-	-		
Zero Gate Voltage Collector Current	Ices	V _{CE} = 600V, V _{GE} = 0V	T _j =25°C	-	-	250	μA	
Lero Gate Voltage Collector Gurrent	ICES		T _i =175°C	-	-	10	mA	
Gate-Emitter Leakage Current	IGES	$V_{CE} = 0V$, $V_{GE} = \pm 20V$		-	-	200	nA	
Gate-Emitter Threshold Voltage	V _{GE (th)}	V _{CE} = +20V, I _C = 35mA		4.0	5.0	6.0	V	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	V _{GE} = +15V, I _C = 35A	T _j =25°C	-	1.50	1.95	V	
			T _j =175°C	-	1.80	-		
Input Capacitance	Cies	V _{CE} =25V		-	2800	-		
Output Capacitance	Coes	V _{GE} =0V		-	140	-	pF	
Reverse Transfer Capacitance	Cres	f=1MHz		-	100	-		
Gate Charge		V _{CC} = 400V						
	Q _G	Ic = 35A V _{GE} = 15V		-	210	-	nC	
Turn-On Delay Time	t _{d(on)}	T₁ = 25°C - 32 Vcc = 400V - 60 Ic = 35A - 200 Vce = 15V - 40		32	-			
Rise Time	t			-	60	-	ns	
Turn-Off Delay Time	t _{d(off)}			-	200	-		
Fall Time	tr			-				
Turn-On Energy	Eon	R _G = 10Ω		-	0.90	-		
		L = 500µH					mJ	
Turn-Off Energy	Eoff		Energy loss include "tail" and FWD		0.85	-	IIIJ	
		(FDRW15S60L) reverse re	covery.					
Turn-On Delay Time	t _{d(on)}	T _i = 175°C		-	33	-	ns	
Rise Time	tr	Vcc = 400V	-	60	-			
Turn-Off Delay Time	t _{d(off)}	Ic = 35A		-	225	-		
Fall Time	tr	V _{GE} = 15V		-	50	-		
Turn-On Energy	Eon	$R_G = 10\Omega$		-	1.40	-		
Turn-Off Energy		L = 500µH					mJ	
	Eoff	Energy loss include "tail" a	nd FWD	-	1.25	-	IIIJ	

Thermal resistance

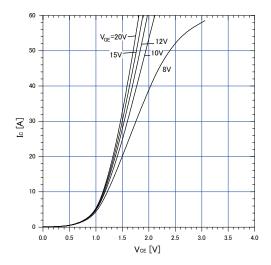
Items	Symbols	Conditions	Characteristics			Unit
			min.	typ.	max.	Unit
Thermal Resistance, Junction-Ambient	R _{th(j-a)}		-	-	50	°C/W
Thermal Resistance Junction to Case	R _{th(i-c)}		-	-	0.641	U/VV

■ Characteristics (Representative)

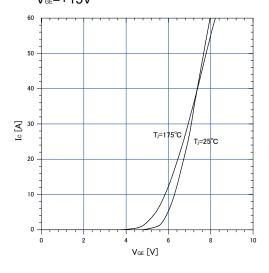
Graph.1 DC Collector Current vs T_c $V_{ce} \ge +15V$, $T_i \le 175$ °C



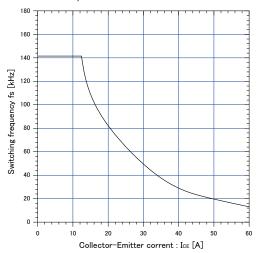
Graph.3
Typical Output Characteristics (VcE-Ic)
T_j=25°C



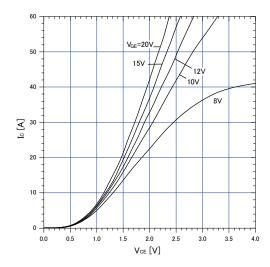
Graph.5 Typical Transfer Characteristics V_{GE} =+15V



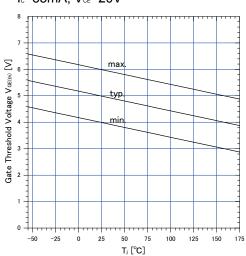
Graph.2 Collector Current vs. switching frequency V_{ce} =+15V, T_{c} ≤175°C, V_{co} =400V, D=0.5, R_{e} =10 Ω , T_{c} =100°C



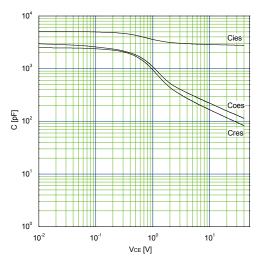
Graph.4
Typical Output Characteristics (VcE-Ic)
T_j=175°C



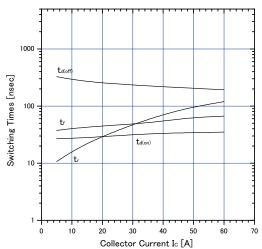
Graph.6
Gate Threshold Voltage vs. T_i
I_c=35mA, V_{cε}=20V



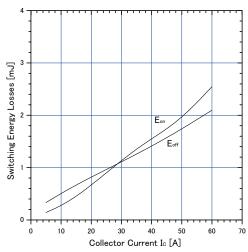
Graph.7 Typical Capacitance V_{c∈}=0V, f=1MHz, T_i=25°C



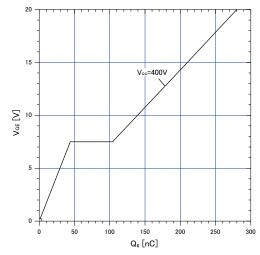
Graph.9 Typical switching time vs. I_{\circ} T_J=175°C, $V_{\circ\circ}$ =400V, L=500 μ H $V_{\circ\varepsilon}$ =15V, R_{\circ} =10 Ω



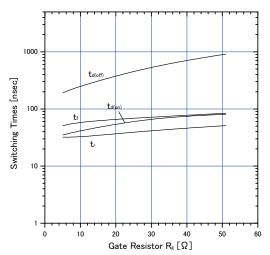
Graph.11 Typical switching losses vs. I_c T_j=175°C, V_{cc} =400V, L=500 μ H V_{ce} =15V, R_c =10 Ω



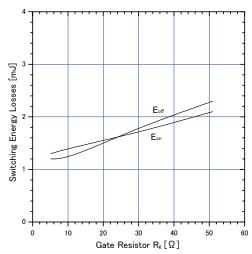
Graph.8 Typical Gate Charge Vcc=400V, Ic=35A, T_i=25°C



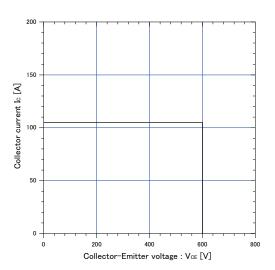
Graph.10 Typical switching time vs. R_s T_s =175°C, V_{cc} =400V, I_c =35A, L=500 μ H V_{se} =15V



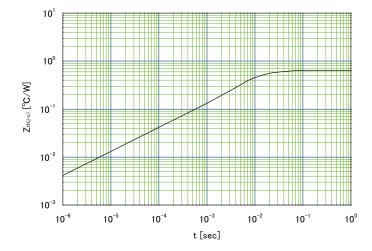
Graph.12 Typical switching losses vs. $R_{\rm s}$ T_i=175°C, $V_{\rm cc}$ =400V, $I_{\rm c}$ =35A, L=500 μ H $V_{\rm gg}$ =15V



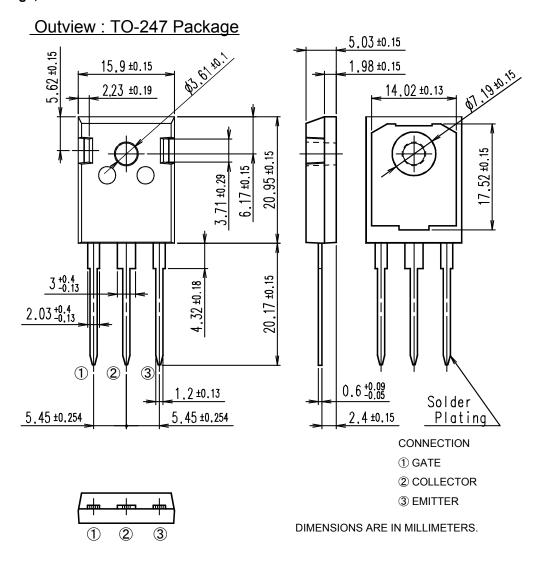
Graph.13 Reverse biased Safe Operating Area $T_1 \le 175^{\circ}C$, $V_{\text{GE}} = +15 \text{V/OV}$, $R_{\text{G}} = 10 \Omega$



Graph.14
Transient thermal resistance of IGBT



■ Outline Drawings, mm



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